

1N5803



Microsemi
 DIODE GEN PURP 75V 1A AXIAL
 Contains lead / RoHS non-compliant
 Discrete Semiconductor Products

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Shopping Process



Specifications

Voltage - Forward (Vf) (Max) @ If:	875mV @ 1A
Voltage - DC Reverse (Vr) (Max):	75V
Speed:	Fast Recovery = 200mA (Io)
Series:	-
Reverse Recovery Time (trr):	25ns
Packaging:	Bulk
Package / Case:	A, Axial
Operating Temperature - Junction:	-65°C ~ 175°C
Mounting Type:	Through Hole
Diode Type:	Standard
Current - Reverse Leakage @ Vr:	1µA @ 75V
Current - Average Rectified (Io):	1A
Capacitance @ Vr, F:	25pF @ 10V, 1MHz

Related products

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Guess You May Looking For

 SIT1602BI-73-XXN-37.500000E -40 TO 85C, 2016, 50PPM, 2.25V-3 SITIME RFQ	 SIT1602BC-83-XXS-66.666660Y -20 TO 70C, 7050, 50PPM, 2.25V-3 SITIME RFQ	 SIT1602BC-72-28E-33.333330D -20 TO 70C, 2016, 25PPM, 2.8V, 3 SITIME RFQ	 SIT1602BC-72-25N-27.000000E -20 TO 70C, 2016, 25PPM, 2.5V, 2 SITIME RFQ	 SIT1602BC-21-33N-60.000000D -20 TO 70C, 3225, 20PPM, 3.3V, 6 SITIME RFQ
 SIT1602BI-71-25S-20.000000E -40 TO 85C, 2016, 20PPM, 2.5V, 2 SITIME RFQ	 SIT1602BI-12-33S-33.300000E -40 TO 85C, 2520, 25PPM, 3.3V, 3 SITIME RFQ	 SIT8008BI-11-33S-22.579200E OSC MEMS 22.5792MHZ LVCMOS SMD SITIME RFQ	 TA-32.768MDE-T OSC MEMS 32.768MHZ CMOS SMD TXC CORPORATION RFQ	 CB3-2C-11M0592 OSC XO 11.0592MHZ HCMOS TTL SMD CTS-Frequency Controls RFQ